

# JT020N120WCD/ABCD/20N120C

## 主要参数 MAIN CHARACTERISTICS

$I_C$	20 A
$V_{CES}$	1200 V
$V_{cesat\_typ}$ (@ $V_{ge}=15V$ )	1.8V

### 用途

- 逆变器
- 电磁炉
- UPS 电源

### APPLICATIONS

- General purpose inverters
- Induction heating(IH)
- UPS

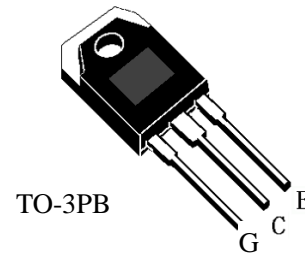
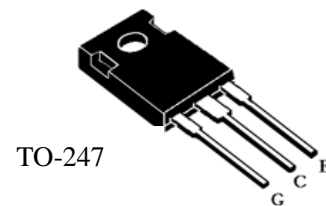
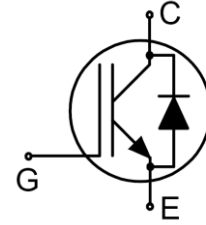
### 产品特性

- 低栅极电荷
- FS 技术
- 通态压降,  $V_{CE(sat)}$ , typ = 1.8V @  $I_C = 20A$  and  $TC = 25^\circ C$
- RoHS 产品

### FEATURES

- Low gate charge
- FS Technology
- saturation voltage:  $V_{CE(sat)}$ , typ = 1.8V @  $I_C = 20A$  and  $TC = 25^\circ C$
- RoHS product

## 封装 Package



## 订货信息 ORDER MESSAGE

订货型号 Order codes	印记 Marking	封装 Package	无卤素 Halogen Free	包装 Packaging	器件重量 Device Weight
JT020N120WCD-W-O-N-B	JT020N120WCD	TO-247	有卤 No	条管 Tube	6.0g(typ)
JT020N120ABCD-AB-O-N-B	JT020N120ABCD	TO-3PB	有卤 No	条管 Tube	5.1g(typ)
20N120C- W-O-N-B	20N120	TO-247	有卤 No	条管 Tube	6.0 g(typ)



# JT020N120WCD/ABCD/20N120C

## 绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
		JT020N120WCD/ABCD/20N120C	
最高集电极—发射极直流电压 Collector-Emmitter Voltage	$V_{CES}$	1200	V
连续集电极极电流 Collector Current-continuous	$I_C$ T=25°C	40	A
	T=100°C	20	A
最大脉冲集电极极电流 (注 1) Collector Current – pulse (note 1)	$I_{CM}$	60	A
最高栅极发射极电压 Gate-Emmitter Voltage	$V_{GES}$	±20	V
安全工作区 Turn-off safe area	-	60	A
耗散功率 Power Dissipation	$P_D$ T <sub>C</sub> =25°C	350	W
最高结温及存储温度 Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~+150	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T <sub>L</sub>	300	°C

\*漏极电流由最高结温限制

\*Collector current limited by maximum junction temperature



**电特性 ELECTRICAL CHARACTERISTICS**

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
<b>关态特性 Off –Characteristics</b>						
集电极—发射极击穿电压 Collector-Emmitter Voltage	$BV_{CES}$	$I_C=500\mu A, V_{GE}=0V$	1200	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{CES}/\Delta T_J$	$I_C=1mA$ , referenced to 25°C	-	0.6	-	V/°C
零栅压下集电极漏电流 Zero Gate Voltage Collector Current	$I_{CES}$	$V_{CE}=1200V, V_{GE}=0V,$ $T_C=25^\circ C$	-	-	0.2	mA
		$T_C=100^\circ C$	-	-	2	mA
		$T_C=150^\circ C$	-	-	2.5	mA
正向栅极体漏电流 Gate-body leakage current, forward	$I_{GESF}$	$V_{CE}=0V, V_{GE}=20V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	$I_{GESR}$	$V_{CE}=0V, V_{GE}=-20V$	-	-	-100	nA
<b>通态特性 On-Characteristics</b>						
阈值电压 Gate-Emmitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}, I_C=600\mu A$	4.5	-	6.5	V
饱和压降 Collector-Emmitter saturation Voltage	$V_{CESAT}$	$V_{GE}=15V, I_C=20A$ $T_C=25^\circ C$	-	1.8	2.45	V
		$T_C=125^\circ C$	-	2.0	-	
		$T_C=150^\circ C$	-	2.1	-	
短路电流（注2） Short Collector current（Note 2）	$I_{C(SC)}$	$V_{GE}=15V, V_{CE}=600V, t_{SC} < 10\mu s, T_C=25^\circ C$	-	160	-	A
<b>动态特性 Dynamic Characteristics</b>						
输入电容 Input capacitance	$C_{ies}$	$V_{CE}=25V, V_{GE}=0V, f=1.0MHz$	-	1600	2400	pF
输出电容 Output capacitance	$C_{oes}$		-	120	190	pF
反向传输电容 Reverse transfer capacitance	$C_{res}$		-	84	130	pF

**电特性 ELECTRICAL CHARACTERISTICS**

开关特性 Switching Characteristics							
开启延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{CE}=600V, I_C=20A, R_G=10\Omega$ $T_C=25^\circ C$ Inductive Load	-	90	-	ns	
上升时间 Turn-On rise time	$t_r$		-	75	-	ns	
关断延迟时间 Turn-Off delay time	$t_{d(off)}$		-	210	-	ns	
下降时间 Turn-Off Fall time	$t_f$		-	100	-	ns	
开启损耗 Turn-on energy	$E_{on}$		-	2.8	-	mJ	
关断损耗 Turn-off energy	$E_{off}$		-	1.1	-	mJ	
总的开关损耗 Total switching energy	$E_{total}$		-	3.9	-	mJ	
栅极电荷总量 Total Gate Charge	$Q_g$	$V_{CE} = 600V, I_C = 20A$ $V_{GE} = 15V$ (note 3, 4)	-	115	-	nC	
反并联二极管特性及最大额定值 Anti-Parallel Diode Characteristics and Maximum Ratings							
正向压降 Diode Forward Voltage	$V_F$	$V_{GE}=0V, I_F=20A$	-	1.7	2.9	V	
反向恢复时间 Diode Reverse recovery time	$t_{rr}$	$V_{GE}=0V, V_R=800V, I_F=20A$ $di_F/dt=200A/\mu s$ (note 4)	-	230	-	ns	
反向恢复电荷 Reverse recovery charge	$Q_{rr}$		-	1.2	-	$\mu C$	

**热特性 THERMAL CHARACTERISTIC**

项 目 Parameter	符 号 Symbol	最大 Max	单 位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.4	$^\circ C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	40	$^\circ C/W$

注释:

- 1: 脉冲宽度由最高结温限制
- 2: 两次短路之间的间隔大于 1 秒时, 允许短路测试的次数最大为 1000 次
- 3: 脉冲测试: 脉冲宽度 $\leq 300\mu s$ , 占空比 $\leq 2\%$
- 4: 基本与工作温度无关

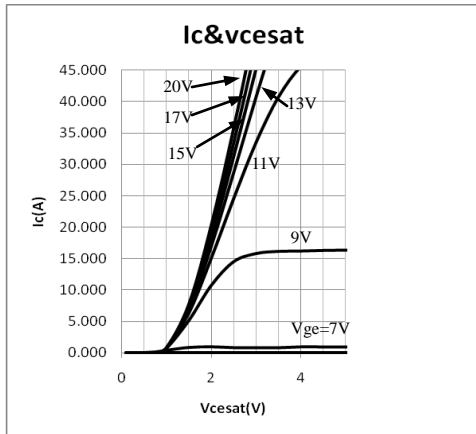
Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: Allowed number of short circuits: <1000; time between short circuits: >1s.
- 3: Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$
- 4: Essentially independent of operating temperature

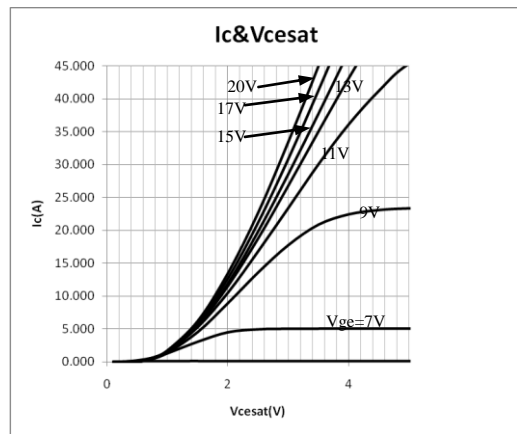


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

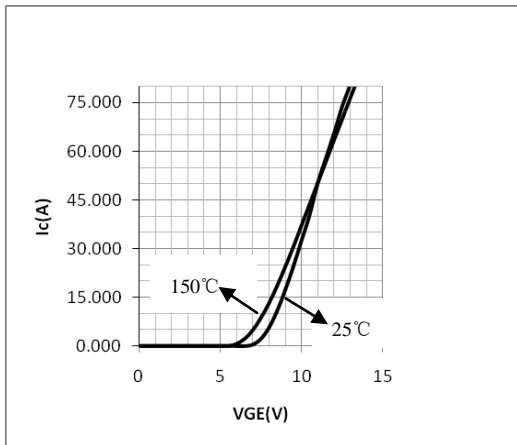
Typical Output Characteristics( $T_j=25^\circ\text{C}$ )



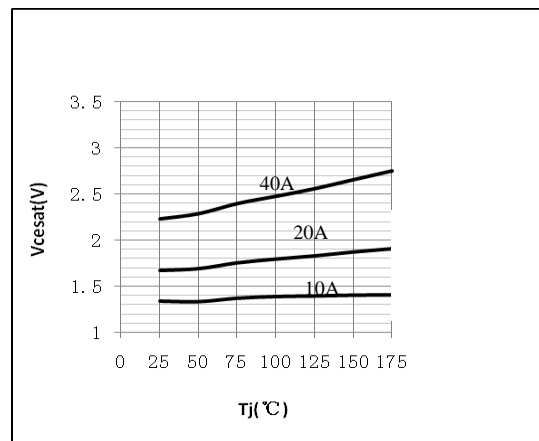
Typical Output Characteristics( $T_j=150^\circ\text{C}$ )



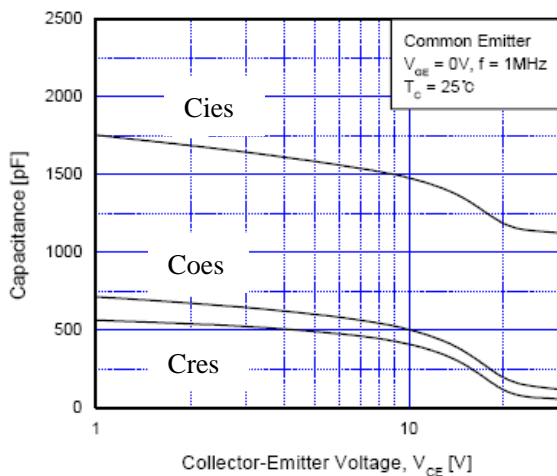
Typical Saturation Voltage Characteristics



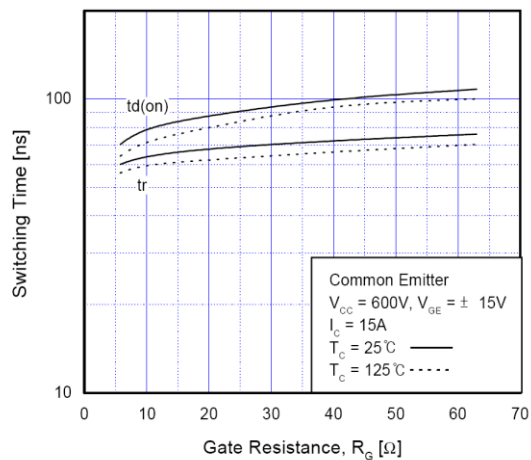
Saturation Voltage vs. Case Temperature at Variant Current Level



Capacitance Characteristics

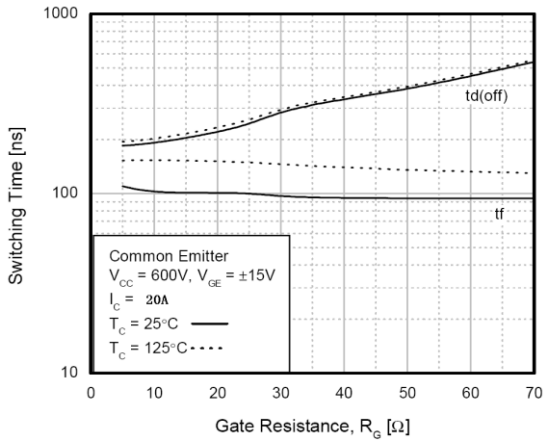


Turn-On Characteristics vs. Gate Resistance

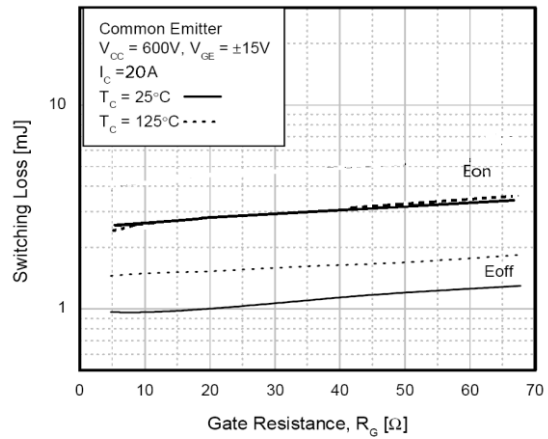




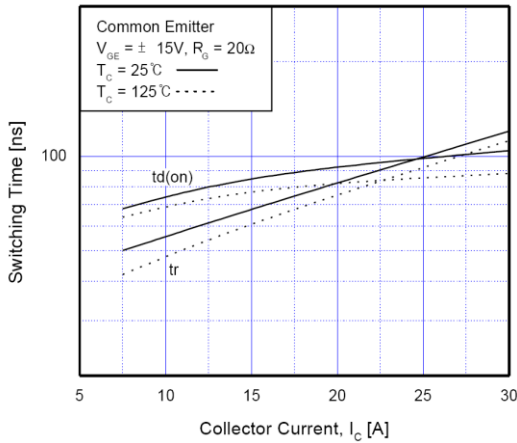
**Turn-Off Characteristics vs. Gate Resistance**



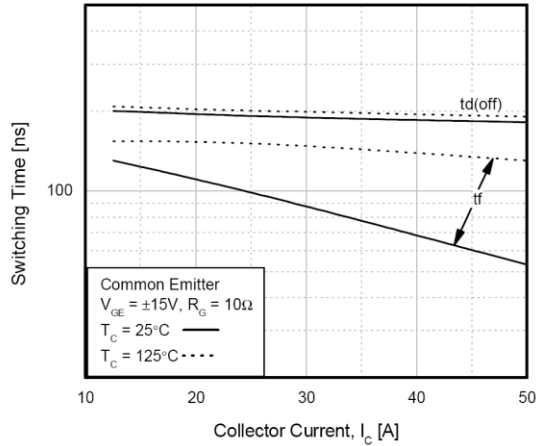
**Switching Loss vs. Gate Resistance**



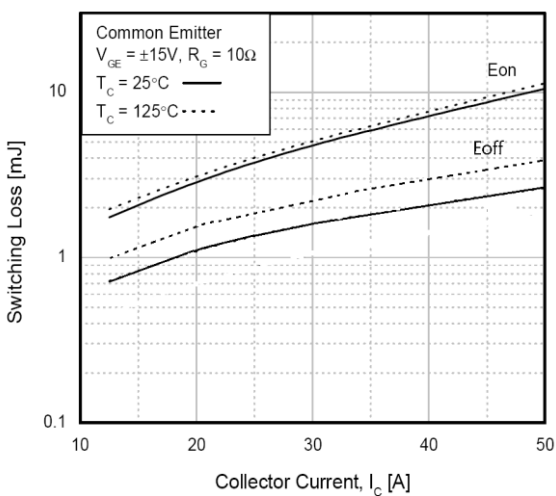
**Turn-On Characteristics vs. Collector Current**



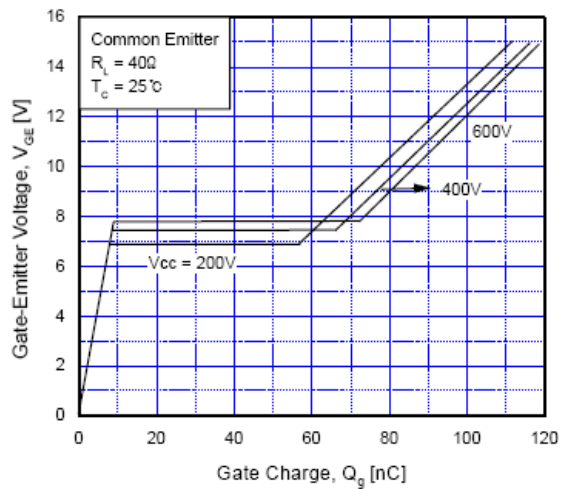
**Turn-Off Characteristics vs. Collector Current**



**Switching Loss vs. Collector Current**

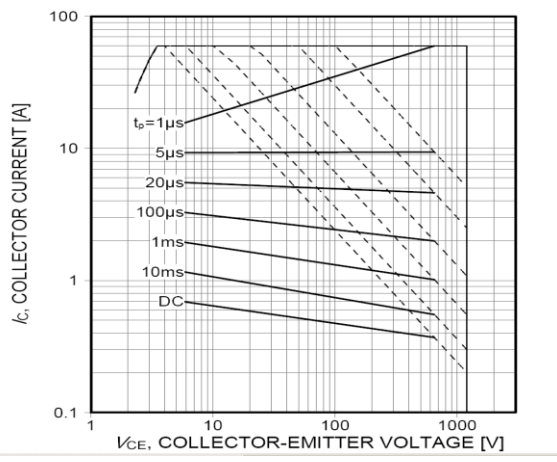


**Gate Charge Characteristics**

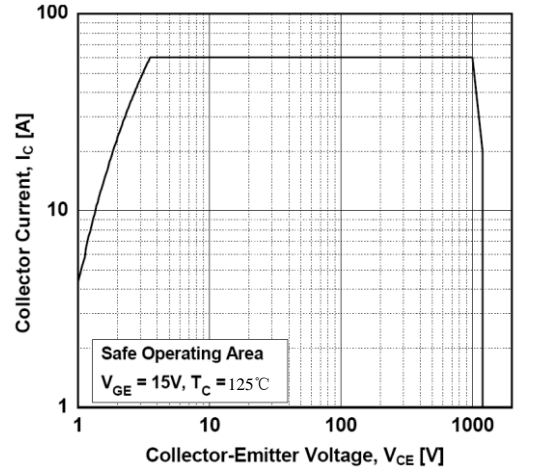




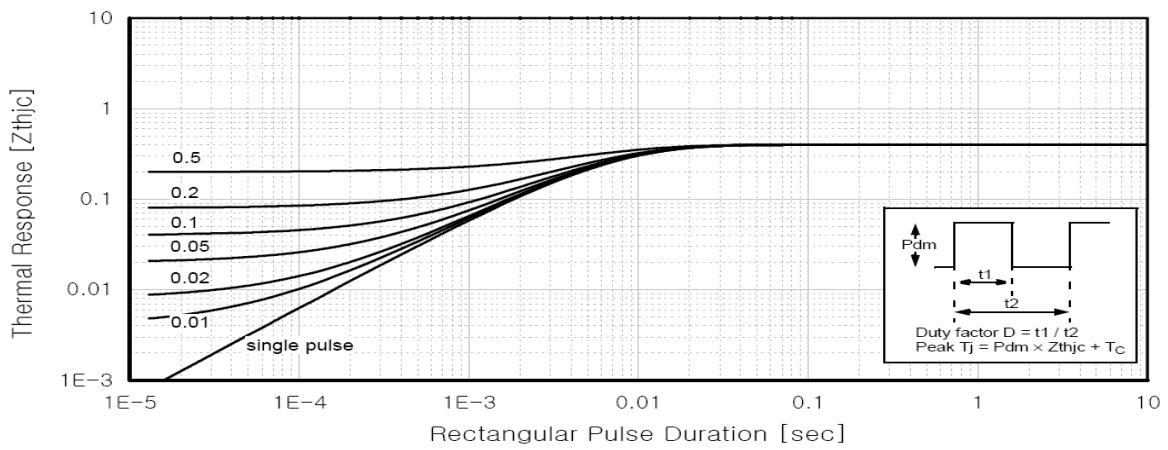
**SOA Characteristics**



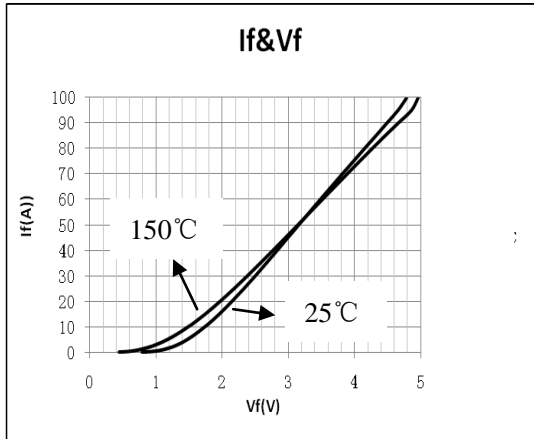
**Turn-Off SOA**



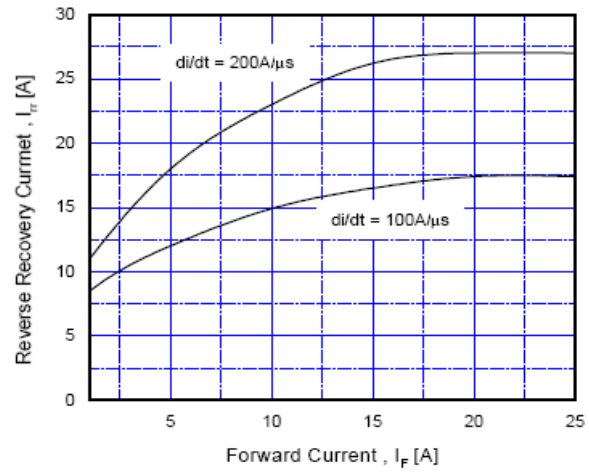
**Transient Thermal Impedance**



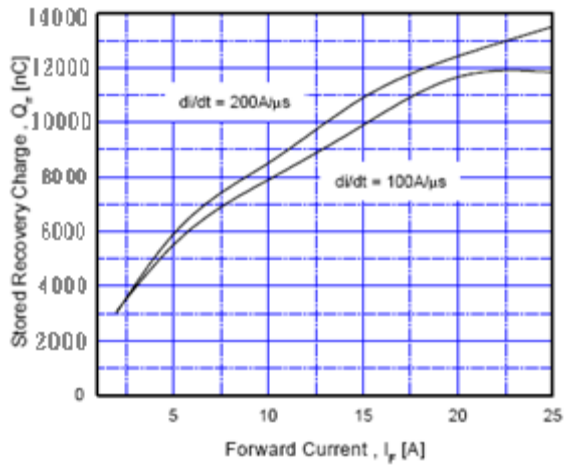
**Forward Characteristics**



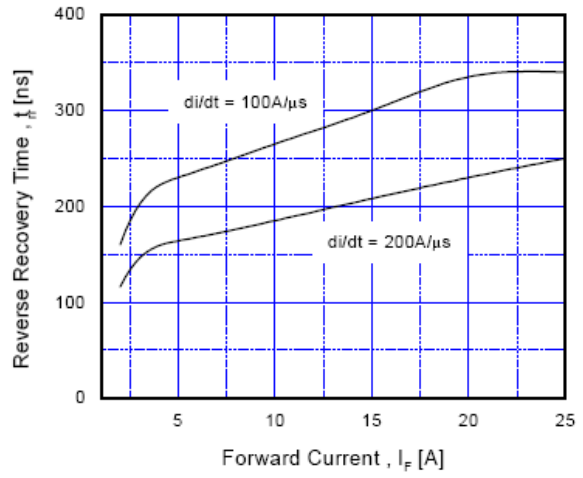
**Reverse Recovery Current**



**Stored Charge**



**Reverse Recovery Time**

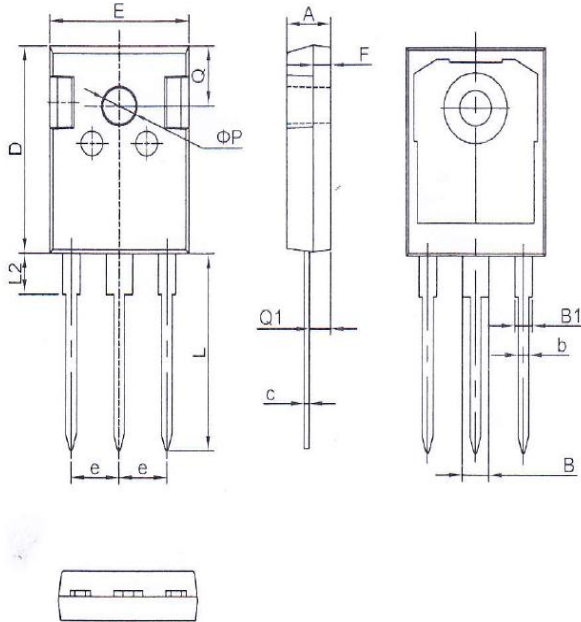




外形尺寸 PACKAGE MECHANICAL DATA

**TO-247**

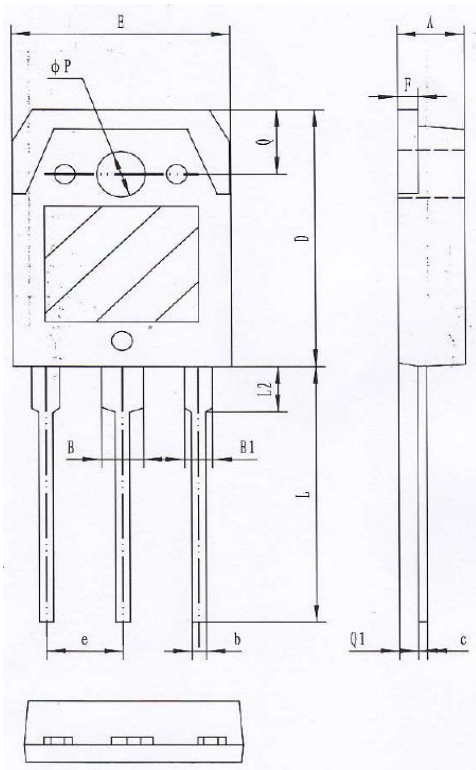
单位 Unit: mm



符号 symbol	MIN	MAX
A	4.90	5.10
B	2.95	3.35
B1	1.95	2.35
b	1.15	1.35
c	0.50	0.70
D	20.90	21.10
E	15.70	15.90
e	5.34	5.54
F	1.90	2.10
L	19.40	20.40
L2	4.03	4.23
Q	6.00	6.40
Q1	2.30	2.50
P	3.50	3.70

**TO-3PB**

单位 Unit: mm



符号 symbol	MIN	MAX
A	4.60	5.00
B	2.90	3.20
B1	1.90	2.20
b	0.90	1.10
c	0.50	0.70
D	19.40	20.40
E	15.40	15.80
e	5.45(TYP)	
F	1.40	1.60
L	19.50	20.50
L2	3.30	3.70
Q	4.90	5.10
Q1	1.30	1.50
P	3.10	3.50